# N-Channel 75 V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>(BR)DSS</sub> (V)	r <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A) <sup>c</sup>	Q <sub>g</sub> (Тур.)	
75	0.0068 at V <sub>GS</sub> = 10 V	75	98 nC	

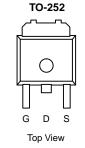
#### FEATURES

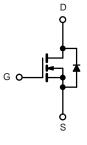
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- 175 °C Junction Temperature
  - DT-Trench Power MOSFET
- Material categorization:



DTU75N75 www.din-tek.jp





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T $_{\rm C}$ =	25 °C, unless othe	rwise noted)			
Parameter		Symbol	Limit ± 20	Unit V	
Gate-Source Voltage	V <sub>GS</sub>				
Continuous Drain Current ( $T_1 = 175 \ ^{\circ}C$ ) <sup>b</sup>	T <sub>C</sub> = 25 °C	L	75		
Commodes Drain Current $(T_J = 175^{\circ}C)^2$	T <sub>C</sub> = 100 °C	I <sub>D</sub>	70 <sup>a</sup>		
Pulsed Drain Current		I <sub>DM</sub>	320	А	
Continuous Source Current (Diode Conduction)		۱ <sub>S</sub>	70 <sup>a</sup>		
Avalanche Current		I <sub>AS</sub>	70		
Single Avalanche Energy (Duty Cycle $\leq$ 1 %)	L = 0.1 mH	E <sub>AS</sub>	300	mJ	
Maximum Power Discinction	T <sub>C</sub> = 25 °C	P <sub>D</sub> -	140	w	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C		3 <sup>b</sup> , 8.3 <sup>b, c</sup>		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum lunation to Ambianta	$t \le 10 \text{ sec}$	R <sub>thJA</sub>	15	18	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		40	50	
Maximum Junction-to-Case		R <sub>thJC</sub>	0.85	1.1	

Notes:

a. Package limited.

b. Surface mounted on 1" x 1" FR4 board.

c.  $t \leq 10$  s.



Parameter	Symbol	Test Conditions	Min.	Typ. <sup>a</sup>	Max.	Unit	
Static	•						
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = 250 \mu A$	75			V	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2	3	4	v	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 75 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	1	
	I <sub>DSS</sub>	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 \text{ °C}$			10	μA	
		V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 175 °C			150		
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 10 V$	75			А	
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A		0.0068	0.0085		
Drain-Source On-State Resistance <sup>b</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A, T <sub>J</sub> = 125 °C			0.0120	0	
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A, T <sub>J</sub> = 175 °C			0.0160	Ω	
Forward Transconductance <sup>b</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 20 A		66		S	
Dynamic	•				•		
Input Capacitance	C <sub>iss</sub>			2550			
Output Capacitance	C <sub>oss</sub>	$V_{GS}$ = 0 V, $V_{DS}$ = 25 V, f = 1 MHz		340		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			260			
Total Gate Charge <sup>c</sup>	Qg			98	120		
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		20		nC	
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			30			
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			10	20		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD}$ = 30 V, $R_L$ = 0.6 $\Omega$		18	25		
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$\rm I_D{\cong}50$ A, $\rm V_{GEN}$ = 10 V, $\rm R_g$ = 2.5 $\Omega$		55	80	ns	
Fall Time <sup>c</sup>	t <sub>f</sub>			15	22		
Source-Drain Diode Ratings and Cha	racteristics (	T <sub>C</sub> = 25 °C)		• 	·		
Pulsed Current	I <sub>SM</sub>				320	А	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>F</sub> = 20 A, V <sub>GS</sub> = 0 V		1	1.5	V	
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 20 A, di/dt = 100 A/μs		25	36	ns	

Notes:

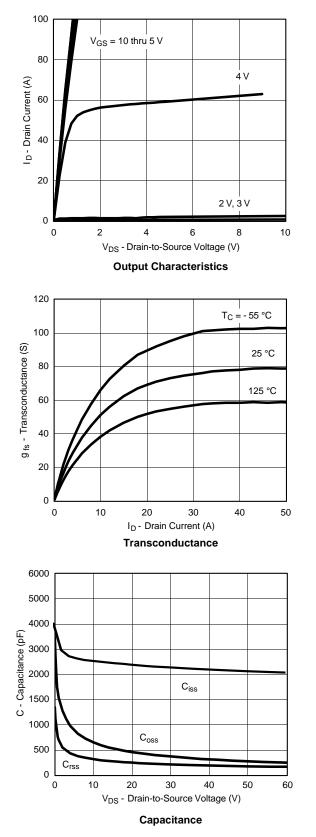
a. For design aid only; not subject to production testing.

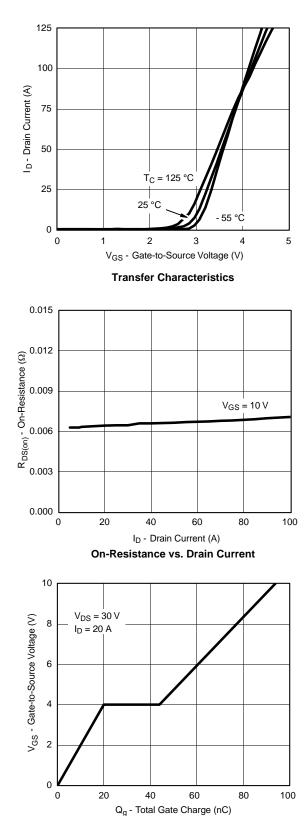
b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS (25 °C unless noted)

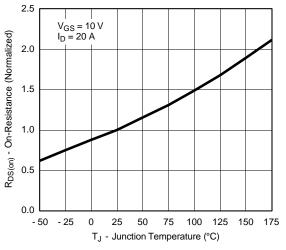




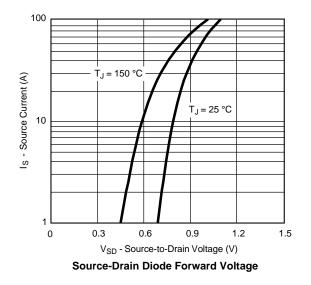
Gate Charge



### TYPICAL CHARACTERISTICS (25 °C unless noted)

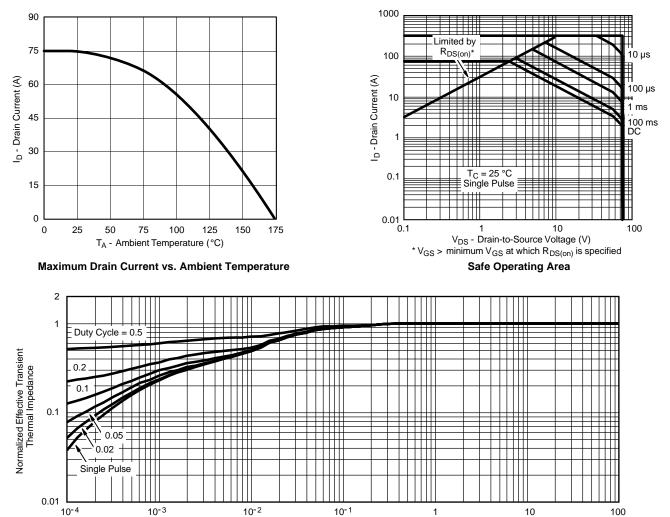


**On-Resistance vs. Junction Temperature** 





#### THERMAL RATINGS



#### Normalized Thermal Transient Impedance, Junction-to-Case

Square Wave Pulse Duration (s)



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